

CMSQ03CP02A06K-HF

P-Channel
RoHS Device
Halogen Free

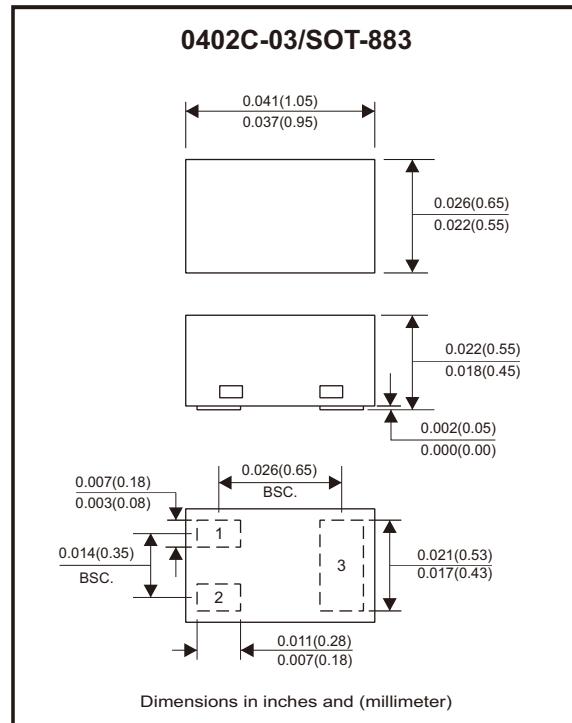


Features

- Surface mount package.
- Reliable and rugged.
- ESD protection.

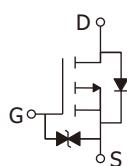
Mechanical data

- Case: 0402C-03/SOT-883 package, molded plastic.
- Mounting position: Any.



Circuit Diagram

- 1 : Gate
- 2 : Source
- 3 : Drain



Maximum Ratings (at $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V_{DSS}	-20	V
Gate-source voltage	V_{GSS}	± 8	V
Continuous drain current	I_D	-800	mA
Power dissipation	P_D	460	mW
Thermal resistance, junction to ambient @ $T_A=25^\circ\text{C}$	$R_{\theta JA}$	245	$^\circ\text{C}/\text{W}$
Operating junction and storage temperature range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics (at $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Static Electrical Characteristics						
Drain-source breakdown voltage	BV_{DSS}	$V_{\text{GS}} = 0\text{V}, I_{\text{D}} = -250\mu\text{A}$	-20			V
Zero gate voltage drain current	I_{DSS}	$V_{\text{DS}} = -16\text{V}, V_{\text{GS}} = 0\text{V}$			-0.6	μA
Gate leakage current	I_{GSS}	$V_{\text{GS}} = \pm 8\text{V}, V_{\text{DS}} = 0\text{V}$			± 10	μA
Gate threshold voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}} = V_{\text{GS}}, I_{\text{D}} = -250\mu\text{A}$	-0.3		-1.0	V
Drain source on-state resistance	$R_{\text{DS(on)}}$	$V_{\text{GS}} = -4.5\text{V}, I_{\text{D}} = -500\text{mA}$		470	560	$\text{m}\Omega$
		$V_{\text{GS}} = -2.5\text{V}, I_{\text{D}} = -500\text{mA}$		590	780	
		$V_{\text{GS}} = -1.8\text{V}, I_{\text{D}} = -100\text{mA}$		700	1100	
		$V_{\text{GS}} = -1.5\text{V}, I_{\text{D}} = -50\text{mA}$		830	1400	
		$V_{\text{GS}} = -1.2\text{V}, I_{\text{D}} = -10\text{mA}$		1100	2200	
Drain forward voltage	V_{SD}	$V_{\text{GS}} = 0\text{V}, I_{\text{S}} = -300\text{mA}$	-0.4		-1.2	V
Dynamic Characteristics						
Input capacitance	C_{iss}	$V_{\text{DS}} = -10\text{V}, V_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$		36		pF
Output capacitance	C_{oss}			11		
Reverse transfer capacitance	C_{rss}			4		

Typical Rating and Characteristic Curves (CMSQ03CP02A06K-HF)

Fig.1 - On-Region Characteristics

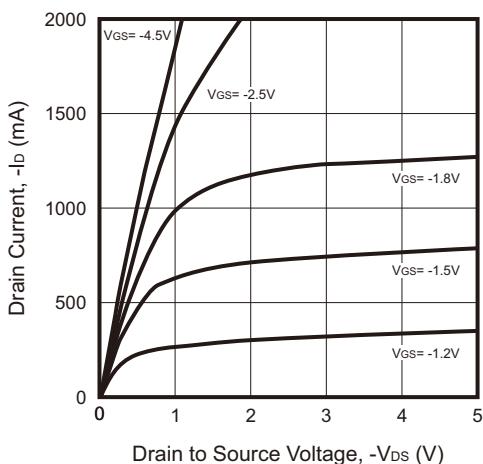


Fig.2 - Transfer Characteristics

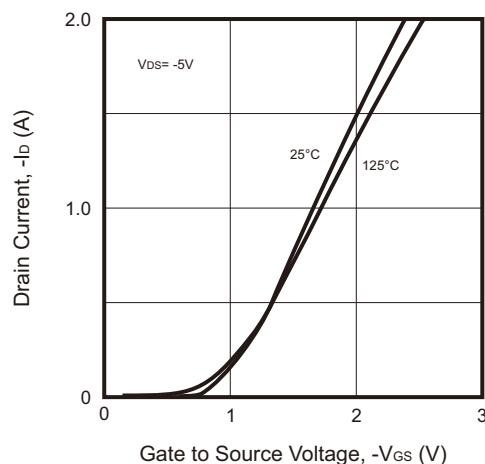


Fig.3 - On-Resistance vs. Drain Current and Gate Voltage

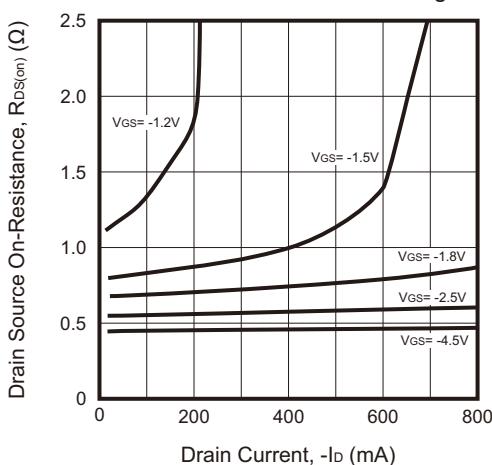


Fig.4 - On-Resistance Variation with Temperature

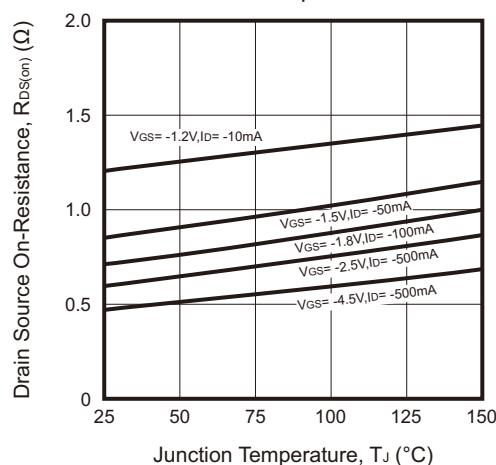


Fig.5 - On-Resistance vs. Gate to Source Voltage

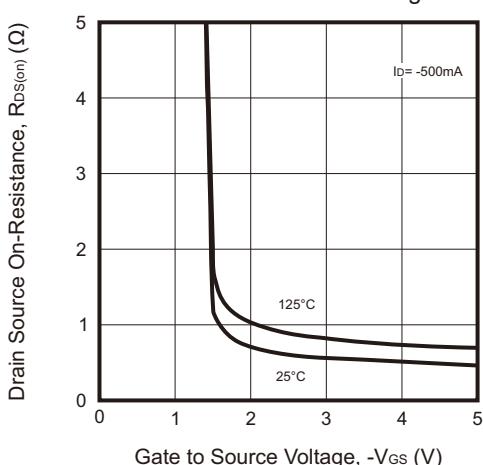
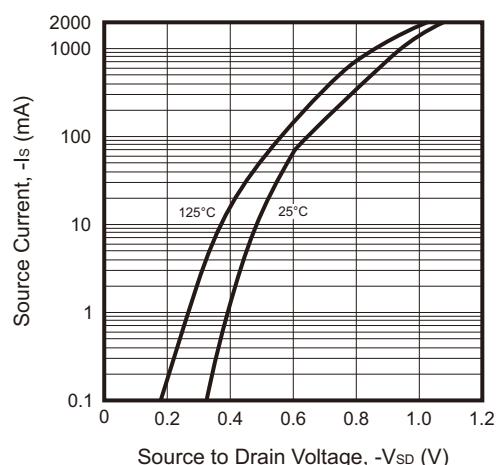


Fig.6 - Diode Forward Voltage vs. Current



Typical Rating and Characteristic Curves (CMSQ03CP02A06K-HF)

Fig.7 - Gate Threshold Variation
vs. Ambient Temperature

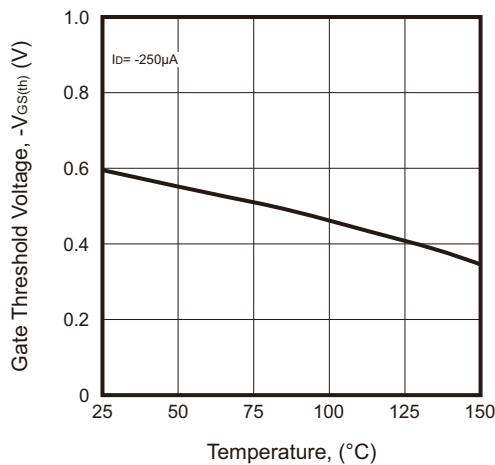


Fig.8 - Breakdown Voltage vs. Temperature

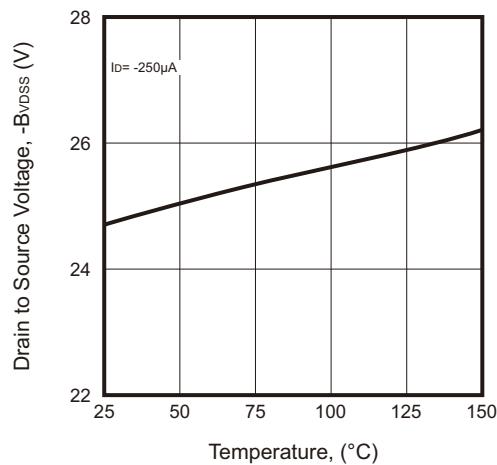
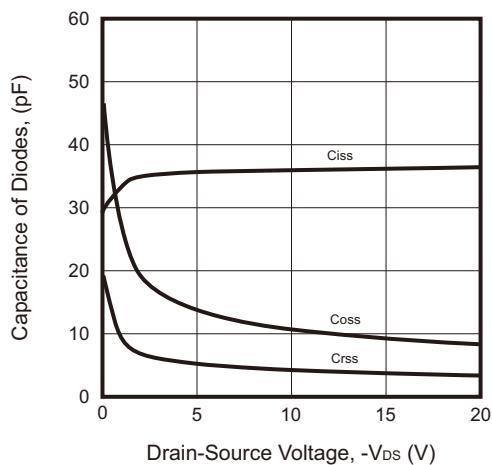
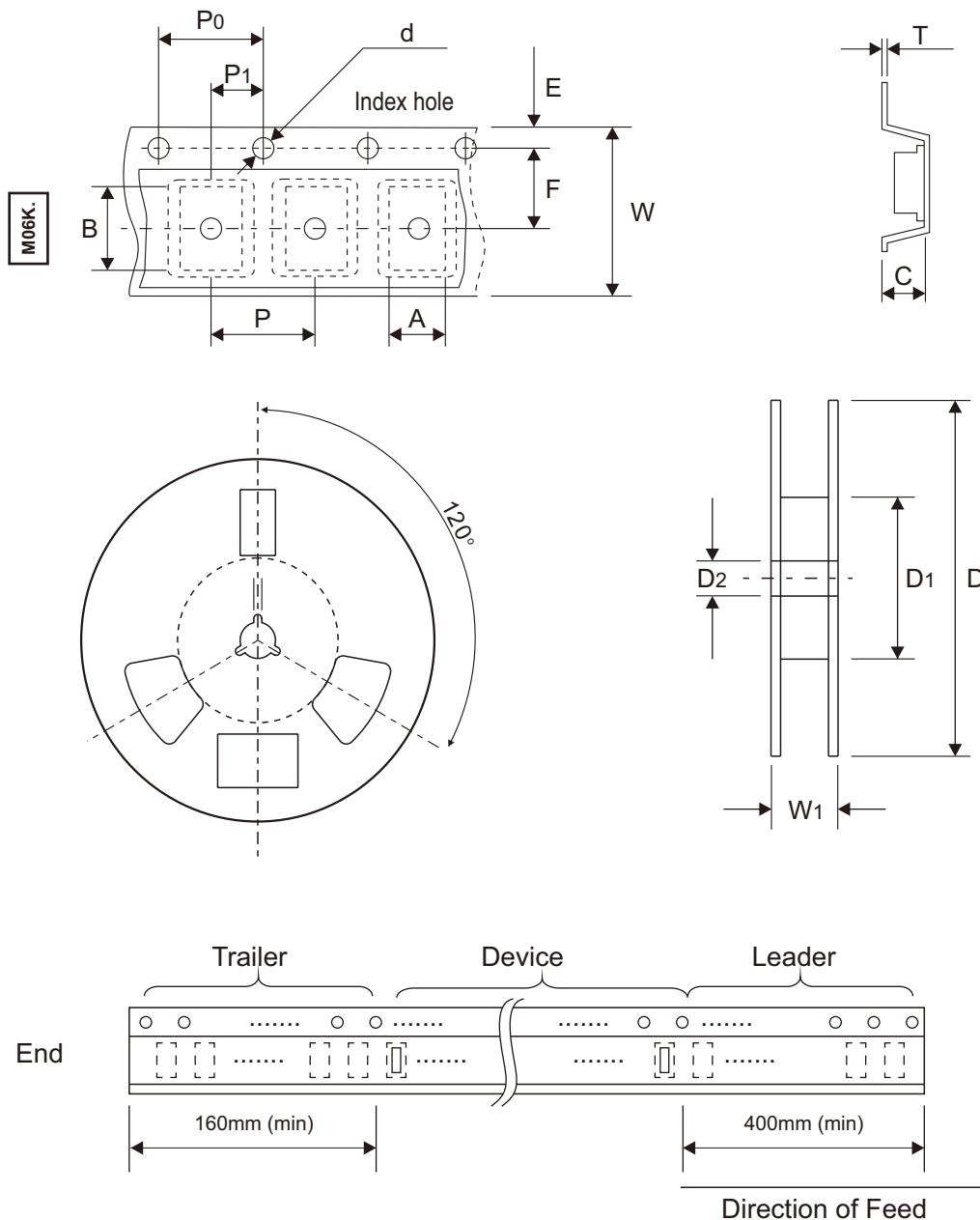


Fig.9 - Capacitance of Diodes



Reel Taping Specification



0402C-03 (SOT-883)	SYMBOL	A	B	C	d	D	D1	D2
	(mm)	0.75 ± 0.05	1.17 ± 0.05	0.65 ± 0.05	$1.50 + 0.10$ $- 0.00$	178.00 ± 1.00	60.00 ± 0.50	13.50 ± 0.20
	(inch)	0.030 ± 0.002	0.046 ± 0.002	0.026 ± 0.002	$0.059 + 0.004$ $- 0.000$	7.008 ± 0.039	2.362 ± 0.020	0.531 ± 0.008

0402C-03 (SOT-883)	SYMBOL	E	F	P	P0	P1	T	W	W1
	(mm)	1.75 ± 0.10	3.50 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.10	$0.20 + 0.02$ $- 0.05$	8.00 ± 0.20	$12.00 + 0.50$ $- 0.00$
	(inch)	0.069 ± 0.004	0.138 ± 0.004	0.157 ± 0.004	0.157 ± 0.004	0.079 ± 0.004	$0.008 + 0.001$ $- 0.002$	0.315 ± 0.008	$0.472 + 0.020$ $- 0.000$

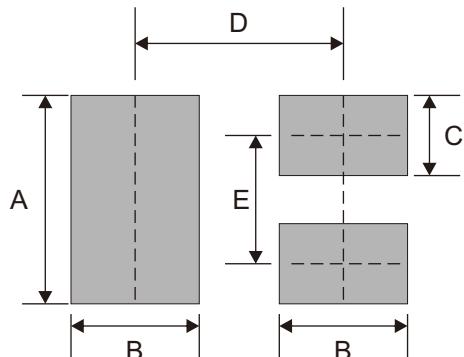
Marking Code

Part Number	Marking Code
CMSQ03CP02A06K-HF	M06K.

M06K.

Suggested P.C.B. PAD Layout

SIZE	0402C-03 (SOT-883)	
	(mm)	(inch)
A	0.65	0.026
B	0.40	0.016
C	0.25	0.010
D	0.65	0.026
E	0.40	0.016



Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
0402C-03 (SOT-883)	5,000	7